

# **isc** Silicon NPN Darlington Power Transistor

# 2SD2385

### DESCRIPTION

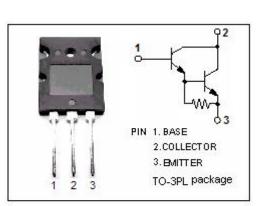
- Collector-Emitter Breakdown Voltage-
- : V<sub>(BR)CEO</sub>= 140V(Min)
- High DC Current Gain : h<sub>FE</sub>= 5000(Min)@I<sub>C</sub>= 7A
- Complement to Type 2SB1556
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

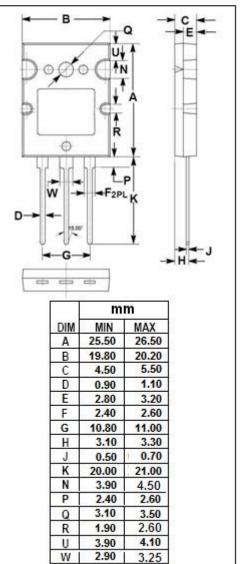
### **APPLICATIONS**

Designed for power amplifier applications

### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL           | PARAMETER                                             | VALUE   | UNIT |  |
|------------------|-------------------------------------------------------|---------|------|--|
| V <sub>CBO</sub> | Collector-Base Voltage                                | 140     | v    |  |
| V <sub>CEO</sub> | Collector-Emitter Voltage                             | 140     | V    |  |
| V <sub>EBO</sub> | Emitter-Base Voltage                                  | 5       | V    |  |
| lc               | Collector Current-Continuous                          | 8       | А    |  |
| Ι <sub>Β</sub>   | Base Current-Continuous                               | 0.1     | A    |  |
| Pc               | Collector Power Dissipation<br>@ T <sub>C</sub> =25°C | 100     | W    |  |
| TJ               | Junction Temperature                                  | 150     | °C   |  |
| T <sub>stg</sub> | Storage Temperature Range                             | -55~150 | °C   |  |





isc website: www.iscsemi.com



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## **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\mathrm{C}$ unless otherwise specified

| SYMBOL               | PARAMETER                            | CONDITIONS                                                           | MIN  | TYP. | МАХ   | UNIT       |
|----------------------|--------------------------------------|----------------------------------------------------------------------|------|------|-------|------------|
| V <sub>(BR)CEO</sub> | Collector-Emitter Breakdown Voltage  | I <sub>C</sub> = 50mA ; I <sub>B</sub> = 0                           | 140  |      |       | V          |
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage | I <sub>C</sub> = 7Α; I <sub>B</sub> = 7mA                            |      |      | 2.5   | V          |
| V <sub>BE(on)</sub>  | Base-Emitter On Voltage              | I <sub>C</sub> = 7A ; V <sub>CE</sub> = 5V                           |      |      | 3.0   | V          |
| I <sub>CBO</sub>     | Collector Cutoff Current             | V <sub>CB</sub> = 140V ; I <sub>E</sub> =0                           |      |      | 5     | μ <b>Α</b> |
| I <sub>EBO</sub>     | Emitter Cutoff Current               | V <sub>EB</sub> = 5V; I <sub>C</sub> =0                              |      |      | 5     | μ Α        |
| h <sub>FE-1</sub>    | DC Current Gain                      | I <sub>C</sub> = 7A ; V <sub>CE</sub> = 5V                           | 5000 |      | 30000 |            |
| h <sub>FE-2</sub>    | DC Current Gain                      | I <sub>C</sub> = 12A ; V <sub>CE</sub> = 5V                          | 2000 |      |       |            |
| Сов                  | Output Capacitance                   | I <sub>E</sub> =0 ; V <sub>CB</sub> = 10V;f <sub>test</sub> = 1.0MHz |      | 110  |       | pF         |
| f⊤                   | Current-Gain—Bandwidth Product       | I <sub>C</sub> = 1A ; V <sub>CE</sub> = 5V                           |      | 30   |       | MHz        |

#### h<sub>FE-1</sub> Classifications

| A          | В          | С           |
|------------|------------|-------------|
| 5000-12000 | 9000-18000 | 15000-30000 |

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